

KS54AHCT 393

KS74AHCT

7-45-23-13
Dual 4-bit Binary Counters

FEATURES

- Function, pin-out, speed and drive compatibility with 54/74ALS logic family
- Low power consumption characteristic of CMOS
- High-Drive-Current outputs:
 $I_{OL} = 8 \text{ mA} @ V_{OL} = 0.5 \text{ V}$
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:
KS74AHCT: -40°C to $+85^{\circ}\text{C}$
KS54AHCT: -55°C to $+125^{\circ}\text{C}$
- Package options include plastic "small outline" packages, standard plastic and ceramic 300-mil DIPs

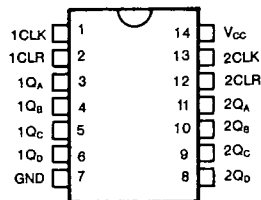
DESCRIPTION

The '393 consists of two independent 4-bit binary counters each with its own clear and clock inputs. N-bit binary counters can be implemented with each package providing the capability of divide-by-256, parallel outputs from each counter stage provided any submultiple of the input count frequency for system timing signals.

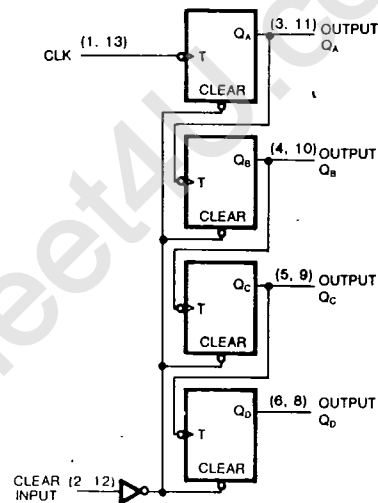
These devices provide speeds and drive capability equivalent to their ALSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V_{CC} and ground.

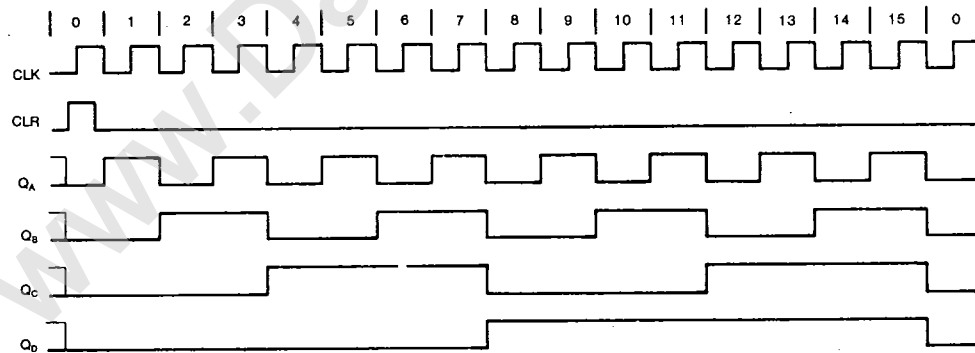
PIN CONFIGURATION



LOGIC DIAGRAM



LOGIC TIMING WAVEFORMS



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294

KS54AHCT 393
KS74AHCT**Dual 4-bit Binary Counters****Absolute Maximum Ratings***

Supply Voltage Range V_{CC} $-0.5V$ to $+7V$
 DC Input Diode Current, I_{IK}
 ($V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$) ± 20 mA
 DC Output Diode Current, I_{OK}
 ($V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$) ± 20 mA
 Continuous Output Current Per Pin, I_O
 ($-0.5V < V_O < V_{CC} + 0.5V$) ± 35 mA
 Continuous Current Through
 V_{CC} or GND pins ± 125 mA
 Storage Temperature Range, T_{stg} $-65^\circ C$ to $+150^\circ C$
 Power Dissipation Per Package, $P_d^\dagger$ 500 mW

* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:

Plastic Package (N): $-12mW/^\circ C$ from $65^\circ C$ to $85^\circ C$
 Ceramic Package (J): $-12mW/^\circ C$ from $100^\circ C$ to $125^\circ C$

Recommended Operating Conditions

Supply Voltage, V_{CC} $4.5V$ to $5.5V$
 DC Input & Output Voltages*, V_{IN} , V_{OUT} . . $0V$ to V_{CC}
 Operating Temperature
 Range KS74AHCT: $-40^\circ C$ to $+85^\circ C$
 KS54AHCT: $-55^\circ C$ to $+125^\circ C$
 Input Rise & Fall Times, t_r , t_f Max 500 ns

* Unused inputs must always be tied to an appropriate logic voltage level (either V_{CC} or GND)

DC ELECTRICAL CHARACTERISTICS ($V_{CC}=5V \pm 10\%$ Unless Otherwise Specified)

Characteristic	Symbol	Test Conditions	T _a = 25°C		KS74AHCT	KS54AHCT	Unit
			Typ	Guaranteed Limits			T _a = -40°C to +85°C
Minimum High-Level Input Voltage	V _{IH}			2.0	2.0	2.0	V
Maximum Low-Level Input Voltage	V _{IL}			0.8	0.8	0.8	V
Minimum High-Level Output Voltage	V _{OH}	V _{IN} =V _{IH} or V _{IL} I _O = -20μA I _O = -4mA	V _{CC} 4.2	V _{CC} - 0.1 3.98	V _{CC} - 0.1 3.84	V _{CC} - 0.1 3.7	V
Maximum Low-Level Output Voltage	V _{OL}	V _{IN} =V _{IH} or V _{IL} I _O = 20μA I _O = 4mA I _O = 8mA	0	0.1 0.26 0.39	0.1 0.33 0.5	0.1 0.4	V
Maximum Input Current	I _{IN}	V _{IN} =V _{CC} or GND		± 0.1	± 1.0	± 1.0	μA
Maximum Quiescent Supply Current	I _{CC}	V _{IN} =V _{CC} or GND I _{OUT} =0μA		8.0	80.0	160.0	μA
Additional Worst Case Supply Current	ΔI _{CC}	per input pin V _I =2.4V other Inputs: at V _{CC} or GND I _{OUT} =0μA		2.7	2.9	3.0	mA



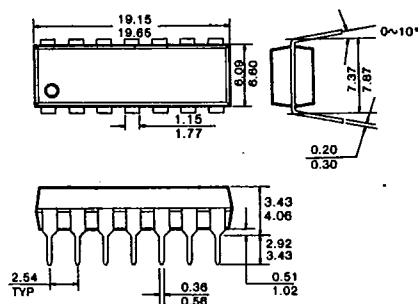
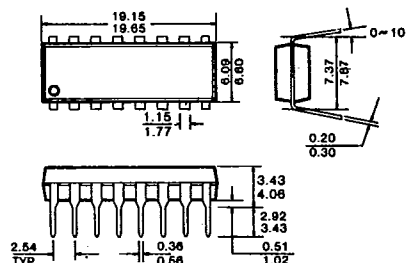
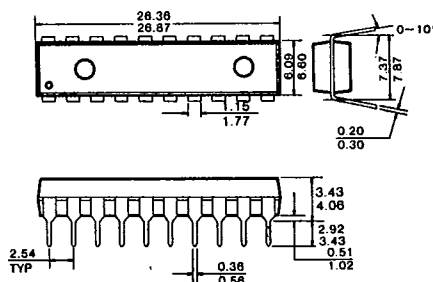
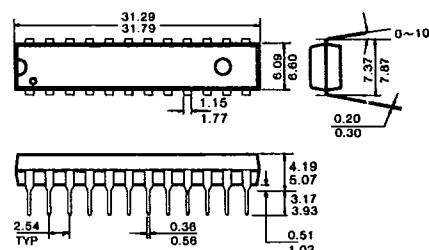
KS54AHCT 393
KS74AHCTT-45-23-13
Dual 4-bit Binary CountersAC ELECTRICAL CHARACTERISTICS (Input $t_r, t_f \leq 2$ ns), AHCT393

Characteristic	Symbol	Conditions†	$T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$	KS74AHCT $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$		KS54AHCT $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$		Unit
			Typ	Min	Max	Min	Max	
Maximum Clock Frequency	f_{max}	$C_L = 50\text{pF}$	50	30		25		MHz
Propagation Delay, A to Q_A	t_{PLH}		14		22		26	ns
	t_{PHL}		14		22		26	
Propagation Delay, A to Q_B	t_{PLH}		18		27		32	ns
	t_{PHL}		18		27		32	
Propagation Delay, A to Q_C	t_{PLH}		20		33		40	ns
	t_{PHL}		20		33		40	
Propagation Delay, A to Q_D	t_{PLH}		26		40		48	ns
	t_{PHL}		26		40		48	
Propagation Delay, CLR to any Q	t_{PHL}		15		25		30	ns
Pulse Width	A Input High or Low	t_w	7	12		15		ns
	CLR High		7	12		15		
Setup Time, CLR Inactive before A	t_{su}		5	8		10		ns
Input Capacitance	C_{IN}		5					pF
Power Dissipation Capacitance*	C_{PD}	(per counter)	40					pF

* C_{PD} determines the no-load dynamic power dissipation: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

† For AC switching test circuits and timing waveforms see section 2.



PACKAGE DIMENSIONS*T-90-20***1. PLASTIC PACKAGES****14-Pin Plastic DIP Units: mm****16-Pin Plastic DIP Units: mm****20-Pin Plastic DIP Units: mm****24-Pin Plastic DIP Units: mm**

7

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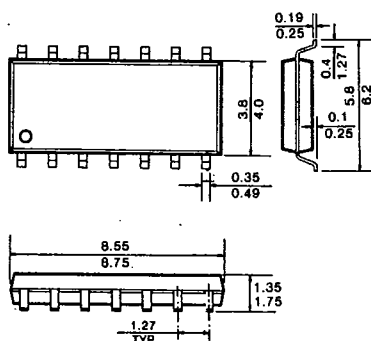
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PACKAGE DIMENSIONS

T-90-20

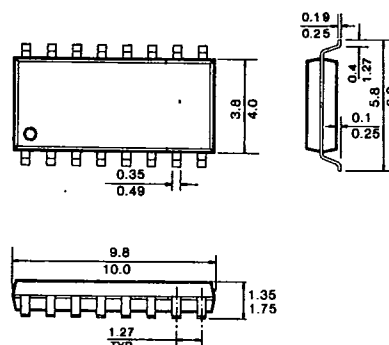
14-Pin SOP

Unit: mm



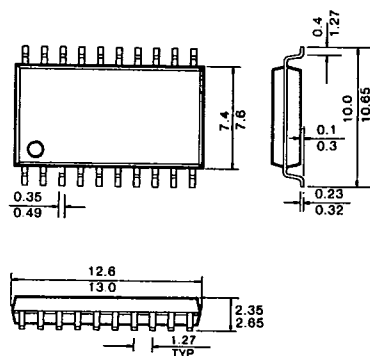
16-Pin SOP

Unit: mm



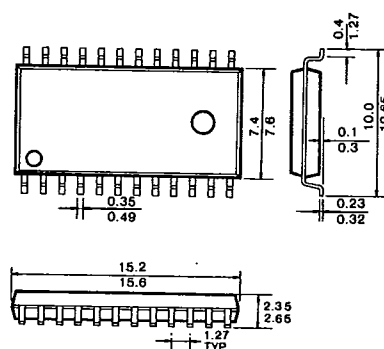
20-Pin SOP

Unit: mm



24-Pin SOP

Unit: mm



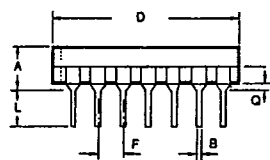
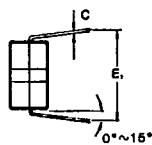
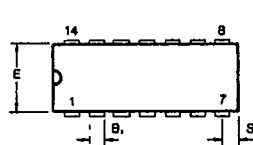
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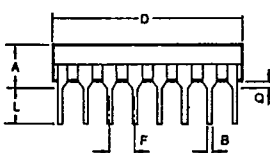
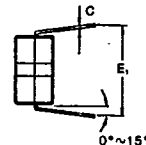
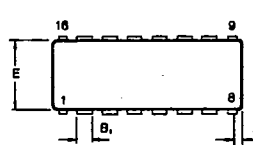
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PACKAGE DIMENSIONS

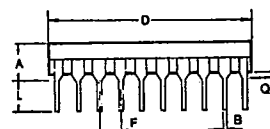
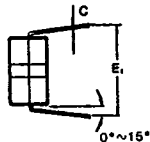
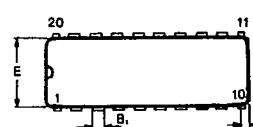
T-90-20

2. CERAMIC PACKAGES**14-Pin Ceramic DIP Units: mm**

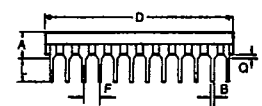
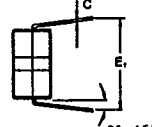
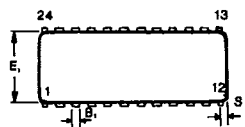
Dim	Millimeters	
	Min	Max
A	—	5.08
B	0.38	0.58
B ₁	1.40	1.78
C	0.20	0.38
D	18.16	19.56
E	8.10	7.49
E ₁	7.62	10.03
F	2.54	
L	3.18	4.19
Q	0.51	1.02
S	1.91	2.29

16-Pin Ceramic DIP Units: mm

Dim	Millimeters	
	Min	Max
A	—	5.08
B	0.38	0.58
B ₁	1.40	1.78
C	0.20	0.38
D	19.05	19.94
E	8.10	7.49
E ₁	7.62	10.03
F	2.54	
L	3.18	4.19
Q	0.51	1.02
S	0.51	1.14

20-Pin Ceramic DIP Units: mm

Dim	Millimeters	
	Min	Max
A	4.06	5.08
B	0.38	0.53
B ₁	1.14	1.52
C	0.20	0.38
D	25.78	26.93
E	8.10	8.60
E ₁	7.77	7.98
F	2.54	
L	3.73	4.01
Q	0.38	0.89
S	0.51	1.14

24-Pin Ceramic DIP Units: mm

Dim	Millimeters	
	Min	Max
A	4.06	5.08
B	0.38	0.53
B ₁	1.14	1.52
C	0.20	0.38
D	31.50	32.84
E	7.24	7.75
E ₁	7.77	7.98
F	2.54	
L	3.73	4.01
Q	0.508	1.778
S	1.85	1.93

7



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783